



DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	I _D T _A = +25°C
-20V	5.5Ω @ $V_{GS} = -4.5V$	-200mA
	7.5Ω @ $V_{GS} = -2.5V$	-170mA

Description

This new generation MOSFET has been designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions

Features

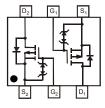
- Dual P-Channel MOSFET
- Low On-Resistance
 - 5.5Ω @ -4.5V
 - 7.5Ω @ -2.5V
 - 11.5Ω @ -1.8V
 - 17.5Ω @ -1.5V
- Very Low Gate Threshold Voltage V_{GS(TH)} <1.15V
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT963
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.0027 grams (approximate)







Top View

Internal Schematic

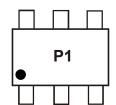
Ordering Information (Note 4)

Part Number	Case	Packaging
DMP210DUDJ-7	SOT963	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information (Note 5)



P1 = Product Type Marking Code

Note: 5. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage	V_{DSS}	-20	V	
Gate-Source Voltage		V_{GSS}	±8	V
Continuous Drain Current (Note 6) V _{GS} = -4.5V	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-200 -150	mA
Continuous Drain Current (Note 6) V _{GS} = -2.5V	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-170 -130	mA
Pulsed Drain Current	$T_P = 10\mu s$	I _{DM}	-600	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 6)	P _D	330	mW
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	377.16	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

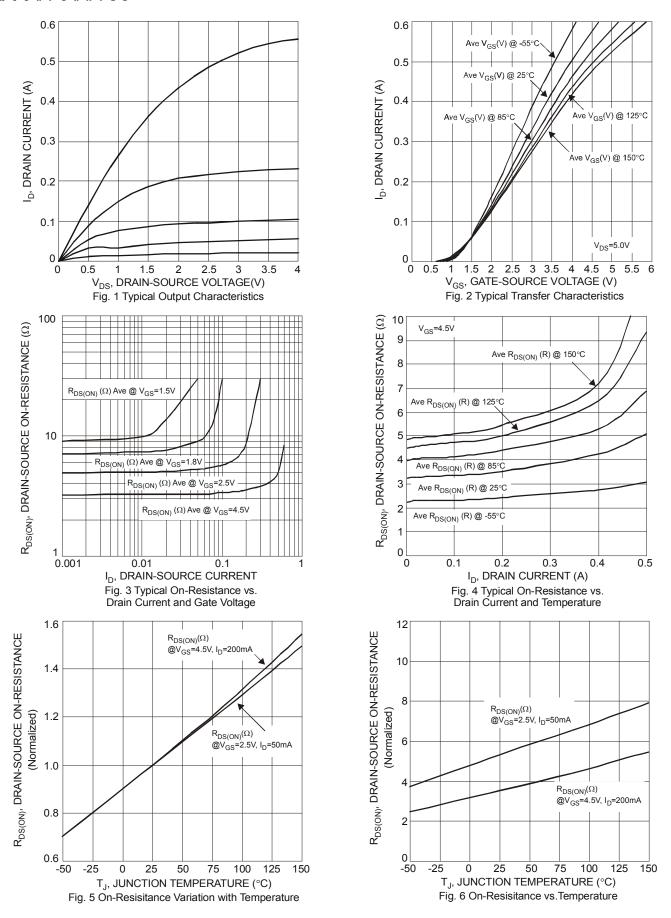
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zoro Coto Voltago Proin Current		_	_	-100	nA	V _{DS} = -16V, V _{GS} = 0V
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-50	nA	$V_{DS} = -5.0V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = \pm 5.0 V, V_{DS} = 0 V$
Oate-Source Leakage				±1	μΑ	$V_{GS} = \pm 8.0 V, V_{DS} = 0 V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(th)}$	-0.45	_	-1.15	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
				5.5		$V_{GS} = -4.5V$, $I_D = -100mA$
			_	7.5	Ω	$V_{GS} = -2.5V, I_D = -50mA$
Static Drain-Source On-Resistance	R _{DS(ON)}			11.5		$V_{GS} = -1.8V, I_D = -20mA$
				17.5		$V_{GS} = -1.5V, I_D = -10mA$
			20			$V_{GS} = -1.2V, I_D = -1mA$
Forward Transfer Admittance	Y _{fs}	150	200	_	mS	$V_{DS} = -10V$, $I_{D} = -0.2A$
Diode Forward Voltage (Note 7)	V_{SD}	-0.5	_	-1.2	V	$V_{GS} = 0V, I_{S} = -115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		13.72	27.44	pF	4514.14
Output Capacitance	Coss		4.01	8.02	pF	V _{DS} = -15V, V _{GS} = 0V -f = 1.0MHz
Reverse Transfer Capacitance	Crss		2.34	4.68	pF	1 = 1.0WH12
SWITCHING CHARACTERISTICS (Note 8)						
Turn-On Delay Time	t _{d(on)}		7.7	_		
Rise Time	tr		19.3	_	ns	V _{GS} = -4.5V, V _{DD} = -15V
Turn-Off Delay Time	t _{d(off)}		25.9	_	115	$I_D = -180 \text{mA}, R_G = 2.0 \Omega$
Fall Time	t _f	_	31.5	_		

Notes:

- 6. Device mounted on 1"x1" FR-4 substrate PC board, with minimum recommended pad layout, single sided.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.







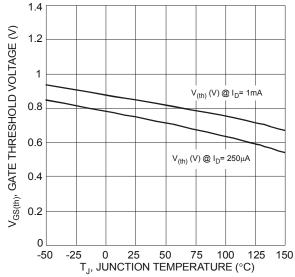
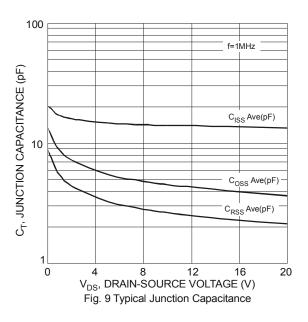
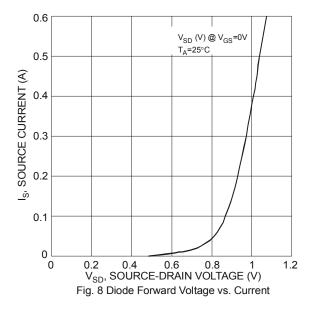


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





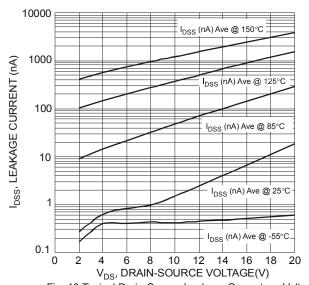
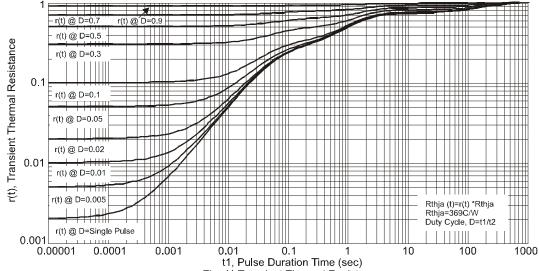


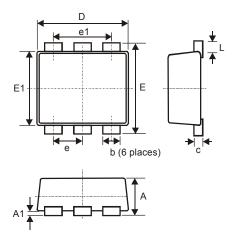
Fig. 10 Typical Drain-Source Leakage Current vs. Voltage





Package Outline Dimensions

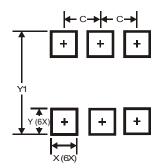
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT963				
Dim	Min	Max	Тур	
Α	0.40	0.50	0.45	
A1	0	0.05	-	
С	0.120	0.180	0.150	
D	0.95	1.05	1.00	
E	0.95	1.05	1.00	
E1	0.75	0.85	0.80	
L	0.05	0.15	0.10	
b	0.10	0.20	0.15	
е	0.35 Typ			
e1	0.70 Typ			
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
C	0.350
Х	0.200
Y	0.200
Y1	1.100



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